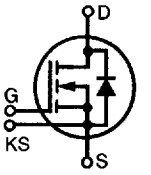
IXYS

MegaMOS™FRED

IXTN36N50

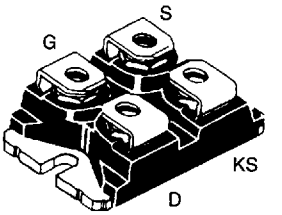
V_{DSS} = 500 V
I_{D25} = 36 A
$R_{DS(on)}$ = 0.12 Ω

N-Channel Enhancement Mode



Symbol	Test Conditions		Maximum Ratings	
V_{DSS}	T_J = 25°C to 150°C		500	V
V_{DGR}	T_J = 25°C to 150°C; R_{GS} = 10 kΩ		500	V
V_{GS}	Continuous		±20	V
V_{GSM}	Transient		±30	V
I_{D25}	T_C = 25°C		36	A
I_{DM}	T_C = 25°C, pulse width limited by T_{JM}		133	A
P_D	T_C = 25°C		400	W
T_J			-40 ... +150	°C
T_{JM}			150	°C
T_{stg}			-40 ... +150	°C
V_{ISOL}	50/60 Hz	t = 1 min	2500	V~
	I_{ISOL} ≤ 1 mA	t = 1 s	3000	V~
M_d	Mounting torque		1.5/13	Nm/lb.in.
	Terminal connection torque (M4)		1.5/13	Nm/lb.in.
Weight			30	g

miniBLOC, SOT-227 B



G = Gate, D = Drain,
S = Source, KS = Kelvin Source

Features

- International standard package miniBLOC (ISOTOP compatible)
- Isolation voltage 3000 V~
- Low $R_{DS(on)}$ HDMOS™ process
- Rugged polysilicon gate cell structure
- Low drain-to-case capacitance (< 50 pF)
- Low package inductance (< 10 nH) - easy to drive and to protect

Symbol	Test Conditions		Characteristic Values (T_J = 25°C, unless otherwise specified) min.	typ.	max.	
V_{DSS}	V_{GS} = 0 V, I_D = 1 mA		500			V
$V_{GS(th)}$	V_{DS} = V_{GS}, I_D = 20 mA		2		4	V
I_{GSS}	V_{GS} = ±20 V_{DC}, V_{DS} = 0				±500	nA
I_{DSS}	V_{DS} = 0.8 • V_{DSS}	T_J = 25°C			400	µA
	V_{GS} = 0 V	T_J = 125°C			2	mA
$R_{DS(on)}$	V_{GS} = 10 V, I_D = 0.5 • I_{D25} Pulse test, t ≤ 300 µs, duty cycle d ≤ 2 %				0.12	Ω

Applications

- AC motor speed control
- DC servo and robot drives
- Uninterruptible power systems (UPS)
- Switch-mode and resonant-mode power supplies
- DC choppers

Advantages

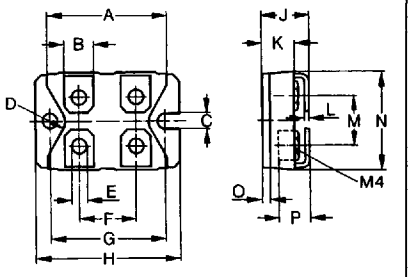
- Easy to mount with 2 screws
- Space savings
- High power density

Symbol	Test Conditions (T$_J$ = 25°C, unless otherwise specified)	Characteristic Values min.	typ.	max.	
g_{fs}	V_{DS} = 10 V; I_D = 0.5 • I_{D25}, pulsed	30	38		S
C_{iss}	V_{GS} = 0 V, V_{DS} = 25 V, f = 1 MHz		8.5		nF
C_{oss}			0.9		nF
C_{rss}			0.3		nF
$t_{d(on)}$	V_{GS} = 10 V, V_{DS} = 0.5 • V_{DSS}, I_D = 0.5 I_{D25} R_G = 1 Ω, (External)			100	ns
t_r				110	ns
$t_{d(off)}$				220	ns
t_f				105	ns
$Q_{g(on)}$	V_{GS} = 10 V, V_{DS} = 0.5 • V_{DSS}, I_D = 0.5 I_{D25}		270	350	nC
Q_{gs}			60	90	nC
Q_{gd}			125	200	nC
R_{thJC}				0.31	K/W
R_{thCK}			0.05		K/W

Source-Drain Diode

Symbol	Test Conditions (T$_J$ = 25°C, unless otherwise specified)	Characteristic Values min.	typ.	max.	
I_S	V_{GS} = 0			36	A
I_{SM}	Repetitive; pulse width limited by T_{JM}			144	A
V_{SD}	I_F = I_S, V_{GS} = 0 V, Pulse test, t ≤ 300 µs, duty cycle d ≤ 2 %			1.5	V
t_{rr}	I_F = I_S, -di/dt = 100 A/µs, V_R = 100 V		600		ns

miniBLOC, SOT 227-B



M4 screws (4x) supplied

Dim.	Millimeter Min.	Max.	Inches Min.	Max.
A	31.5	31.7	1.241	1.249
B	7.8	8.2	0.307	0.323
C	4 0	-	0.158	-
D	4 1	4.3	0.162	0.169
E	4 1	4 3	0 162	0.169
F	14 9	15 1	0 587	0.595
G	30 1	30 3	1 186	1 193
H	38.0	38 2	1 497	1.505
J	11 8	12 2	0 465	0.481
K	8 9	9.1	0.351	0.359
L	0.75	0.85	0.030	0.033
M	12.6	12.8	0.496	0.504
N	25.2	25.4	0.993	1.001
O	1.95	2.05	0.077	0.081
P	-	5.0	-	0.197

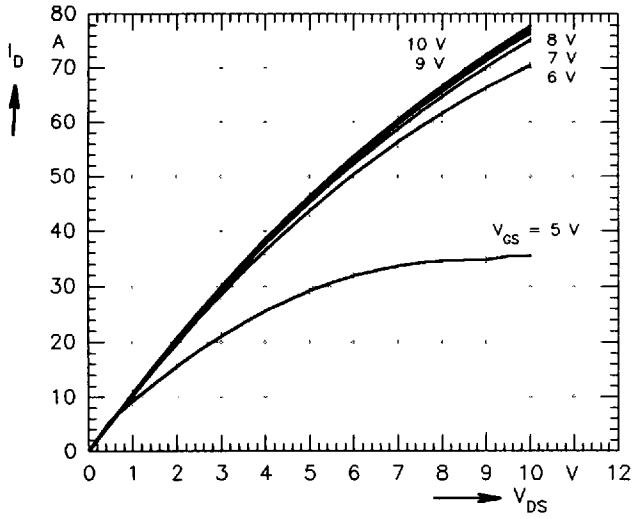


Fig. 1 Typ output characteristics, $I_D = f(V_{DS})$

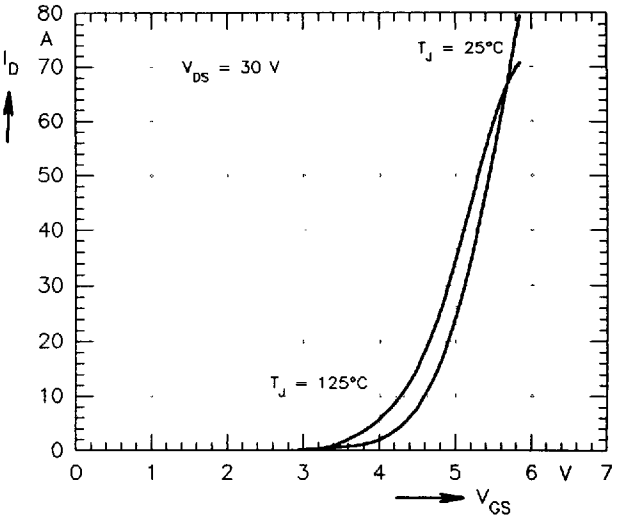


Fig. 2 Typ. transfer characteristics, $I_D = f(V_{GS})$

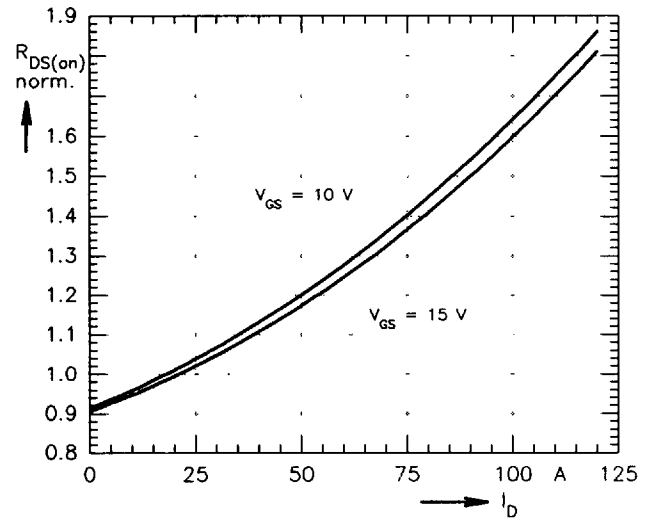


Fig. 3 Typ. normalized $R_{DS(on)} = f(I_D)$

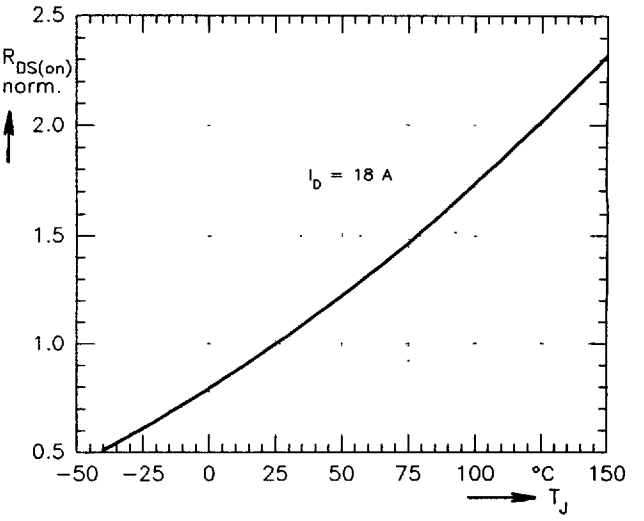


Fig. 4 Typ. normalized $R_{DS(on)} = f(T_J)$

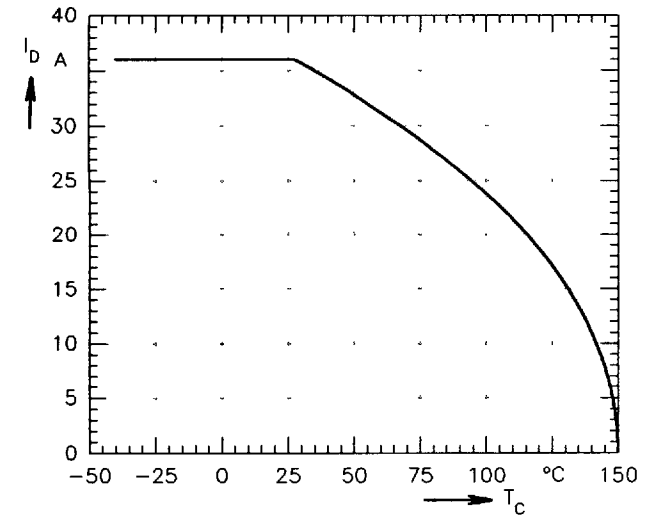


Fig. 5 Continuous drain current $I_D = f(T_C)$

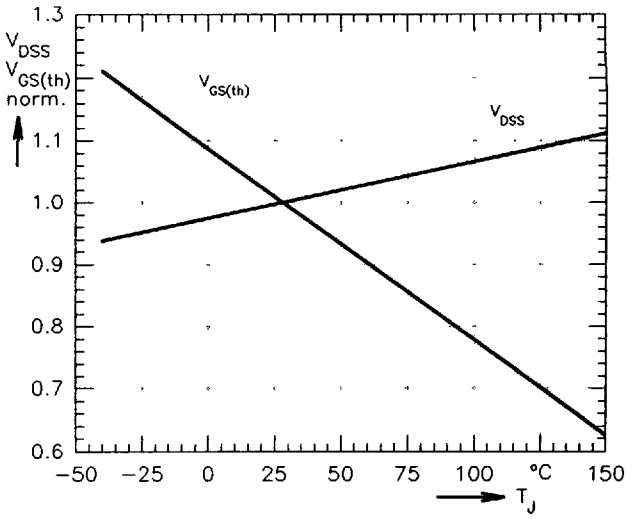


Fig. 6 Typ. normalized $V_{DSS} = f(T_J)$, $V_{GS(th)} = f(T_J)$

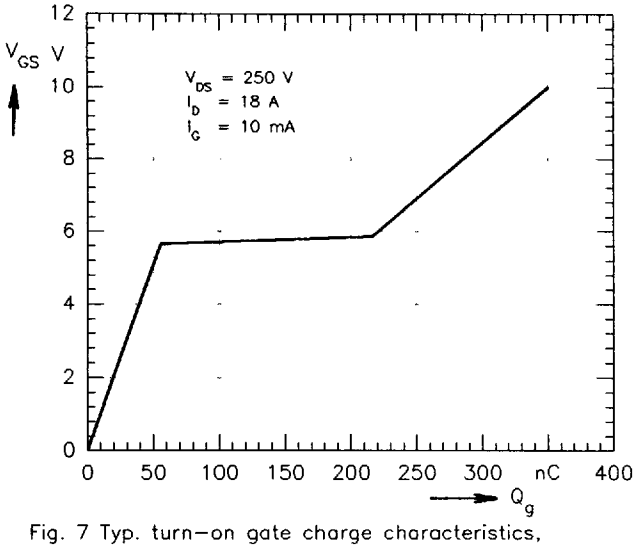


Fig. 7 Typ. turn-on gate charge characteristics, V_{GS} = f (Qg)

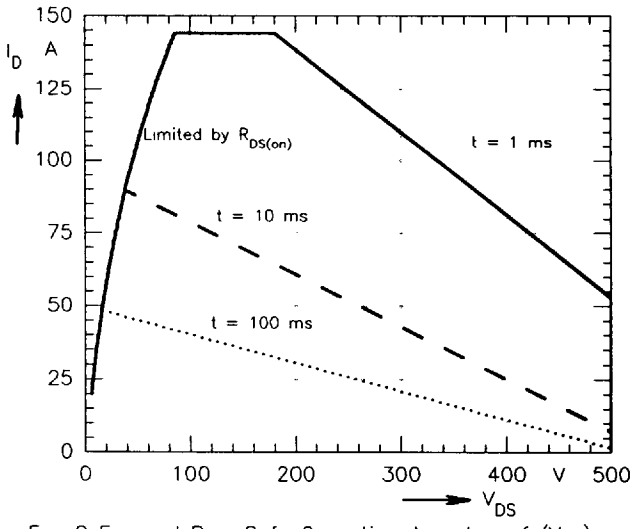


Fig. 8 Forward Bias Safe Operating Area I_D = f (V_{DS})

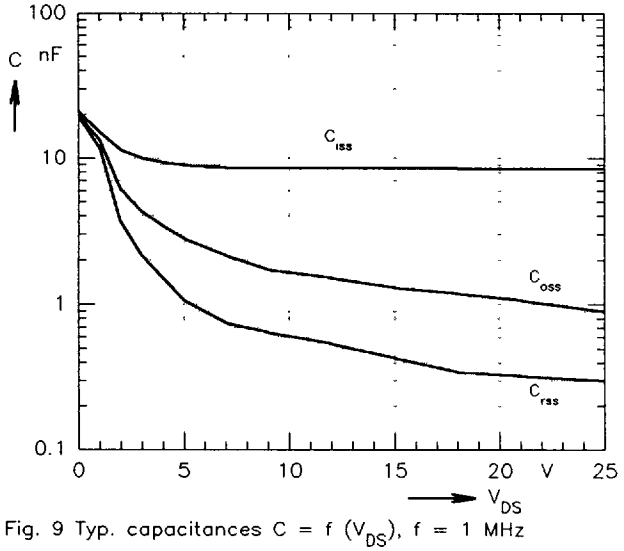


Fig. 9 Typ. capacitances C = f (V_{DS}), f = 1 MHz

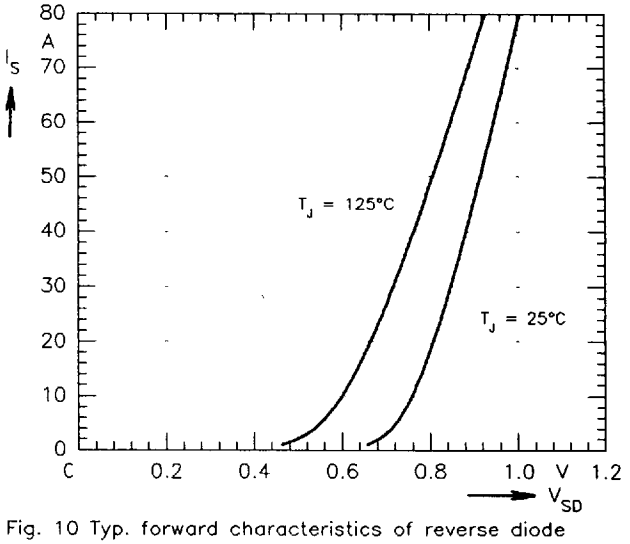


Fig. 10 Typ. forward characteristics of reverse diode I_S = f (V_{SD})

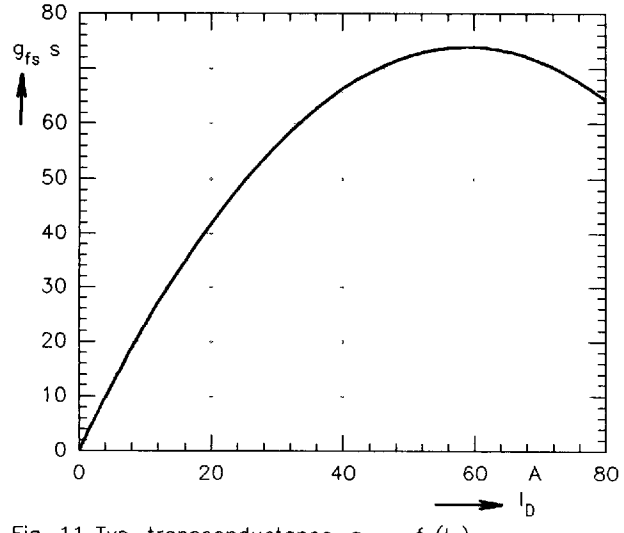


Fig. 11 Typ. transconductance, g_{fs} = f (I_D)

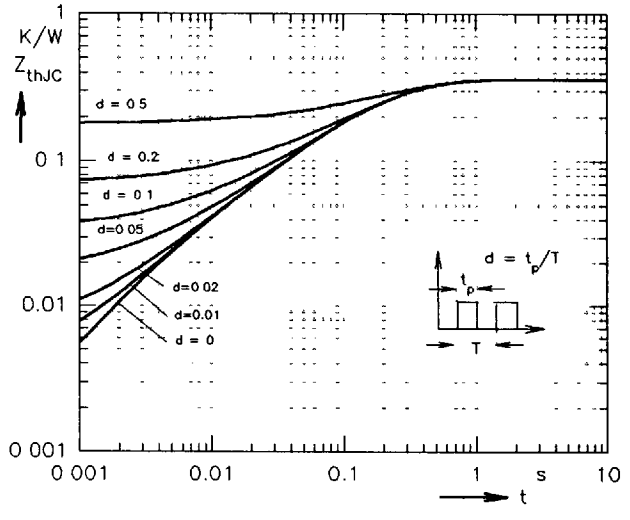


Fig. 12 Transient thermal resistance, Z_{thJC} = f (t)

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